

Chip Varistors / Ceramic Transient Voltage Suppressors

Series/Type: CT0603S14AHSG, CA05P4S14THSG

Date: November 2025

The following products presented in this data sheet are being withdrawn.

| Ordering Code | Substitute Product | Date of Withdrawal | Deadline Last Orders | Last Shipments |
|-----------------|--------------------|--------------------|----------------------|----------------|
| B72714A8140S160 | | 2021-10-01 | 2022-01-07 | 2022-04-08 |
| B72500T8140S160 | | 2021-10-01 | 2022-01-07 | 2022-04-08 |

Please contact your nearest TDK sales office if you need support in selecting a suitable substitute. The addresses of our worldwide sales network are presented at www.tdk-electronics.tdk.com/sales.

Multilayer varistors (MLVs)
High-speed series
SMD
Type designation system for high-speed series, single chips

| | | | | |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|----|---|
| CT | 0402 | V150 | HS | G |
| Construction: CT \triangleq Single chip with nickel barrier termination (AgNiSn) | | | | |
| Case sizes: 0402 0603 | | | | |
| Maximum RMS operating voltage (V_{RMS}): S5 \triangleq 4 V S14 \triangleq 14 V L25 \triangleq 25 V Or: Indication of the varistor voltage: V150 \triangleq 150 V V275 \triangleq 275 V | | | | |
| Internal coding | | | | |
| Taping mode: G \triangleq 180-mm reel, 7" G2 \triangleq 330-mm reel, 13" | | | | |

Multilayer varistors (MLVs)

High-speed series

SMD

Type designation system for high-speed series, array

| CA | 05 | M2 | S10 | T | 100H | G |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----|----|-----|---|------|---|
| Construction: CA \triangleq Chip array with nickel barrier termination (AgNiSn) | | | | | | |
| Case sizes: 05 \triangleq 0508 array 06 \triangleq 0612 array | | | | | | |
| Number of elements per component: M2 \triangleq Array with two elements P4 \triangleq Array with four elements | | | | | | |
| Maximum RMS operating voltage (V_{RMS}): S10 \triangleq 10 V S14 \triangleq 14 V Typical varistor voltage (V_v): V150 \triangleq 150 V | | | | | | |
| Internal coding | | | | | | |
| High-speed series 100H \triangleq Matched capacitance varistor (MCV array with $C_{yp} = 10 \cdot 10^0 = 10$ pF) HS \triangleq 4-fold array | | | | | | |
| Taping mode: G \triangleq 180-mm reel, 7" | | | | | | |

Multilayer varistors (MLVs)

High-speed series

SMD

Description

The high-speed series comprises a range of multilayer ceramic varistors for protection against ESD on data lines.

Features

- ESD protection level acc. to ISO 10605, IEC 61000-4-2 level 4
- Capacitance ratings down to 0.6 pF
- Low insertion loss
- Low leakage current
- No signal distortion
- Long-term ESD stability
- Bidirectional protection
- RoHS-compatible
- Suitable for lead-free soldering
- PSpice simulation models available

Applications

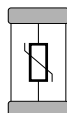
- ESD protection for high-speed data lines such as USB 2.0, firewire, IEEE 1394 interfaces, RF antennas, RF modules
- Selected types for ESD protection for high-speed automotive data lines (e.g. CAN bus, FlexRay)
- ESD protection for I/O ports of video and audio lines
- Integrated solutions for connectors in mobile communication and handheld devices

Design

- Multilayer technology
- Flammability rating better than UL 94 V-0
- Termination (see “Soldering directions”):
 - CT and CA types with nickel barrier terminations (AgNiSn), recommended for lead-free soldering, and compatible with tin/lead solder.

Single chip

Internal circuit



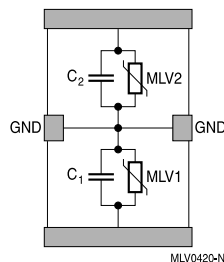
MLV0006-H

Available case sizes:

| EIA | Metric |
|------|--------|
| 0402 | 1005 |
| 0603 | 1608 |

Matched capacitance varistor array (MCV array)

Internal circuit



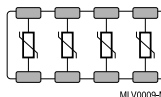
MLV0420-N

Available case sizes:

| EIA | Metric | Version |
|------|--------|--------------|
| 0508 | 1220 | 2-fold array |

4-fold array

Internal circuit



MLV0009-MI

Available case sizes:

| EIA | Metric | Version |
|------|--------|--------------|
| 0508 | 1220 | 4-fold array |
| 0612 | 1632 | 4-fold array |

Multilayer varistors (MLVs)
High-speed series
SMD
General technical data for single chips

| | | | | |
|----------------------------------|----------------------------|-------------------|------------|----|
| Maximum RMS operating voltage | | $V_{RMS,max}$ | 4 ... 25 | V |
| Maximum DC operating voltage | | $V_{DC,max}$ | 5.5 ... 32 | V |
| Contact discharge ESD capability | to IEC 61000-4-2 | $V_{ESD,contact}$ | 8 | kV |
| Air discharge ESD capability | to IEC 61000-4-2 | $V_{ESD,air}$ | 15 | kV |
| Maximum surge current | (8/20 μ s) | $I_{surge,max}$ | 1 ... 5 | A |
| Typical capacitance | (1 MHz, 1 V) | C_{typ} | 0.6 ... 15 | pF |
| Maximum clamping voltage | | $V_{clamp,max}$ | 66 ... 290 | V |
| Operating temperature | for 0402 | T_{op} | -40/+85 | °C |
| Operating temperature | for 0603 | T_{op} | -55/+125 | °C |
| Operating temperature | for 0603, automotive types | T_{op} | -55/+150 | °C |
| Storage temperature | for 0402 | LCT/UCT | -40/+125 | °C |
| Storage temperature | for 0603 | LCT/UCT | -55/+150 | °C |
| Response time | | t_{resp} | < 0.5 | ns |

General technical data for arrays

| | | | | |
|--------------------------------------|-------------------|-------------------|-------------------------------------------------------------------|----|
| Maximum RMS operating voltage | | $V_{RMS,max}$ | 10 ... 14 | V |
| Maximum DC operating voltage | | $V_{DC,max}$ | 12 ... 16 | V |
| Contact discharge ESD capability | to IEC 61000-4-2 | $V_{ESD,contact}$ | 8 | kV |
| Air discharge ESD capability | to IEC 61000-4-2 | $V_{ESD,air}$ | 15 | kV |
| Maximum surge current | (8/20 μ s) | $I_{surge,max}$ | 1 ... 5 | A |
| Typical capacitance for 4-fold array | (1 MHz, 1 V) | C_{typ} | 4 x 3 ... 4 x 10 | pF |
| Typical capacitance for MCV array | (1 MHz, 1 V) | C_{typ} | Matched capacitance 2 x 10 (ΔC between elements < 3%) | pF |
| Maximum clamping voltage | | $V_{clamp,max}$ | 59 ... 350 | V |
| Operating temperature | for 4-fold arrays | T_{op} | -40/+125 | °C |
| Operating temperature | for MCV arrays | T_{op} | -55/+125 | °C |
| Storage temperature | for 4-fold arrays | LCT/UCT | -40/+125 | °C |
| Storage temperature | for MCV arrays | LCT/UCT | -55/+150 | °C |
| Response time | | t_{resp} | < 0.5 | ns |

Multilayer varistors (MLVs)
High-speed series
SMD
Electrical specifications and ordering codes for single chips
Maximum ratings ($T_{op,max}$)

| Type | Ordering code | $V_{RMS,max}$ V | $V_{DC,max}$ V | $I_{surge,max}$ (8/20 μ s) A | W_{max} (ESD) ¹⁾ mJ | $T_{op,max}$ $^{\circ}$ C |
|--------------------|-----------------|--------------------|-------------------|----------------------------------------|----------------------------------------|------------------------------|
| Single chip | | | | | | |
| CT0402S5ARFG | B72590T7050S160 | 4 | 5.5 | - | - | +85 |
| CT0603S5ARFG | B72500T7050S160 | 4 | 5.5 | - | - | +125 |
| CT0402S14AHSG | B72590T8140S160 | 14 | 16 | 2 | 30 | +85 |
| CT0402V150HSG | B72590T8151V060 | 14 | 16 | 1 | 30 | +85 |
| CT0402V150RFG | B72590T7151V060 | 14 | 16 | - | - | +85 |
| CT0402V275RFG | B72590T7271V060 | 14 | 16 | - | - | +85 |
| CT0402V90RFG | B72590T7900V060 | 14 | 16 | - | - | +85 |
| CT0603S14AHSG | B72500T8140S160 | 14 | 16 | 5 | 30 | +125 |
| CT0603S14AHSG_E | B72500E8140S160 | 14 | 16 | 5 | 30 | +150 ²⁾ |
| CT0603V150RFG | B72500T7151V060 | 14 | 16 | - | - | +125 |
| CT0603V150RFG_E | B72500E7151V060 | 14 | 16 | - | - | +150 ²⁾ |
| CT0603L25HSG | B72500T8250L060 | 25 | 32 | 5 | 50 | +125 |
| CT0603L25HSG_E | B72500E8250L060 | 25 | 32 | 5 | 50 | +150 ²⁾ |

Characteristics ($T_A = 25^{\circ}$ C)

| Type | V_V (1 mA) V | ΔV_V % | $V_{clamp,max}$ V | I_{clamp} (8/20 μ s) A | C_{typ} (1 MHz, 1 V) pF | C_{max} (1 MHz, 1 V) pF |
|--------------------|----------------------|-------------------|----------------------|------------------------------------|---------------------------------|---------------------------------|
| Single chip | | | | | | |
| CT0402S5ARFG | 255 | ± 15 | - | - | 0.6 | 1 |
| CT0603S5ARFG | 255 | ± 15 | - | - | 0.6 | 1 |
| CT0402S14AHSG | 28 | ± 20 | 66 | 1 | 10 | 15 |
| CT0402V150HSG | 150 | ± 35 | 290 | 1 | 2 | 3 |
| CT0402V150RFG | 150 | ± 35 | - | - | 2 | 3 |
| CT0402V275RFG | 275 | ± 30 | - | - | 1.5 | 2 |
| CT0402V90RFG | 105 | ± 15 | - | - | 2.2 | 3 |
| CT0603S14AHSG | 28 | ± 20 | 66 | 1 | 15 | 30 |
| CT0603S14AHSG_E | 28 | ± 20 | 66 | 1 | 15 | 30 |
| CT0603V150RFG | 150 | ± 35 | - | - | 3 | 5 |
| CT0603V150RFG_E | 150 | ± 35 | 290 | 1 | 3 | 5 |
| CT0603L25HSG | 61 | ± 15 | 120 | 1 | 10 | 15 |
| CT0603L25HSG_E | 61 | ± 15 | 120 | 1 | 10 | 15 |

Note:

Typ CT0603S14AHSG_E, CT0603V150RFG_E and CT0603L25HSG_E are qualified acc. to AEC-Q200 with $T_{op} = 150^{\circ}$ C.

- 1) To IEC 61000-4-2, level 4
- 2) Qualified acc. to AEC-Q200

Multilayer varistors (MLVs)

High-speed series

SMD

Electrical specifications and ordering codes for arrays

Maximum ratings ($T_{op,max}$)

| Type | Ordering code | $V_{RMS,max}$ V | $V_{DC,max}$ V | $I_{surge,max}$ (8/20 μ s) A | W_{max} (ESD) ¹⁾ mJ | $T_{op,max}$ $^{\circ}$ C |
|-----------------|-----------------|--------------------|-------------------|----------------------------------------|----------------------------------------|------------------------------|
| 2-fold array | | | | | | |
| CA05M2S10T100HG | B72812Q1120S160 | 10 | 12 | 5 | - | +125 ²⁾ |
| 4-fold array | | | | | | |
| CA05P4S14THSG | B72714A8140S160 | 14 | 16 | 2 | 30 | +85 |
| CA06P4V150THSG | B72724A8151V062 | 14 | 16 | 1 | 30 | +85 |

Characteristics ($T_A = 25\text{ }^{\circ}$ C)

| Type | V_V (1 mA) V | ΔV_V % | $V_{clamp,max}$ V | I_{clamp} (8/20 μ s) A | C_{typ} (1 MHz, 1 V) pF | C_{max} (1 MHz, 1 V) pF |
|-----------------|----------------------|-------------------|----------------------|------------------------------------|---------------------------------|---------------------------------|
| 2-fold array | | | | | | |
| CA05M2S10T100HG | 26 | ± 20 | 60 | 1 | 10 | 15 |
| 4-fold array | | | | | | |
| CA05P4S14THSG | 28 | ± 15 | 59 | 1 | 10 | 15 |
| CA06P4V150THSG | 150 | ± 20 | 350 | 1 | 3 | 5 |

Further characteristics

| Type | Absolute capacitance deviation between array elements ³⁾ % | Maximum relative capacitance change %/ K | Dissipation factor $\tan \delta$ (@ 1 MHz, 1 V_{RMS} , 25 $^{\circ}$ C) | $P_{diss,max}$ mW | V_{LD} (300 ms) V | V_{jump} (60 s) V |
|-----------------|--------------------------------------------------------------------------|---------------------------------------------|------------------------------------------------------------------------------------|----------------------|---------------------------|---------------------------|
| 2-fold array | | | | | | |
| CA05M2S10T100HG | ≤ 3 | 0.1 | $< 50 \cdot 10^{-3}$ | 3 | 27 | 28 |

1) To IEC 61000-4-2, level 4

2) Qualified acc. to AEC-Q200

3) Absolute value of $(C_1 - C_2) / \text{minimum } \{C_1, C_2\}$, with C_1, C_2 denoting the two individual capacitances of the 2-fold array.

Multilayer varistors (MLVs)

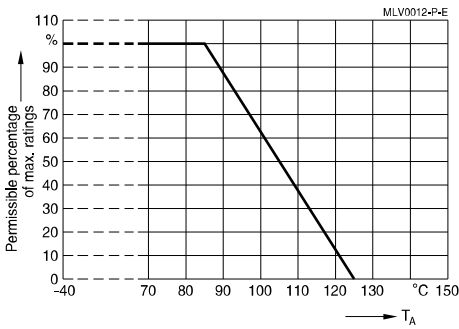
High-speed series

SMD

Temperature derating

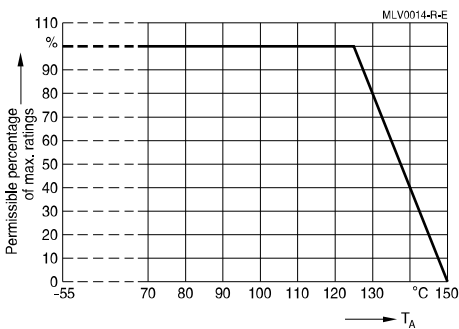
Climatic category:

–40/+85 °C for chip size 0402 single chip and 4-fold arrays



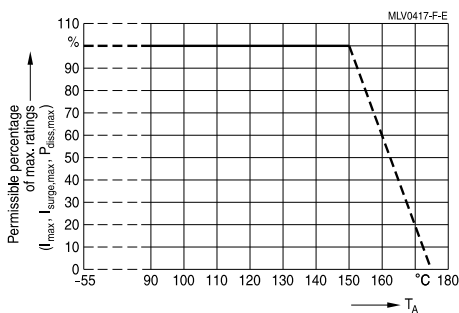
Climatic category:

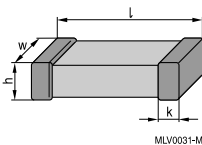
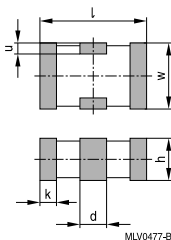
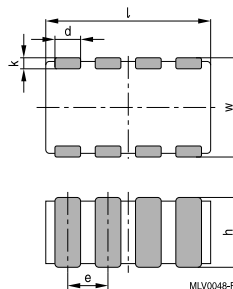
–55/+125 °C for chip size 0603 single chip and MCV arrays



Climatic category:

–55/+150 °C for chip size 0603 single chip, only automotive types



Multilayer varistors (MLVs)
High-speed series
SMD
Dimensional drawings
Single chip

2-fold MCV array

4-fold array

Dimensions in mm

| Case size EIA / mm | l | w | h | d | e | k | u |
|------------------------------------|------------|------------|-----------|------------|------------|----------------|---------------|
| 0201 / 0603 Single chip | 0.60 ±0.03 | 0.30 ±0.03 | 0.33 max. | - | - | 0.15 ±0.05 | - |
| 0402 / 1005 Single chip | 1.00 ±0.15 | 0.50 ±0.10 | 0.6 max. | - | - | 0.10 ... 0.30 | - |
| 0508 / 1220 2-fold MCV array | 2.00 ±0.20 | 1.25 ±0.15 | 0.9 max. | 0.50 ±0.20 | - | 0.30 ±0.20 | 0.20 ±0.10 |
| 0508 / 1220 4-fold array | 2.00 ±0.20 | 1.25 ±0.20 | 0.9 max. | 0.30 ±0.10 | 0.50 ±0.10 | 0.20 +0.2/-0.1 | - |
| 0603 / 1608 Single chip | 1.60 ±0.15 | 0.80 ±0.10 | 0.9 max. | - | - | 0.10 ... 0.40 | - |
| 0612 / 1632 4-fold array | 3.20 ±0.20 | 1.60 ±0.15 | 0.9 max. | 0.40 ±0.15 | 0.80 ±0.15 | 0.20 ±0.10 | - |

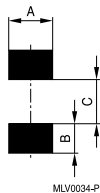
Multilayer varistors (MLVs)

High-speed series

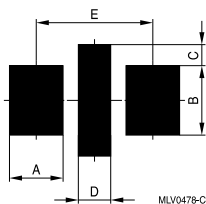
SMD

Recommended solder pad layout

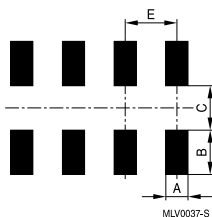
Single chip



2-fold MCV array



4-fold array



Dimensions in mm

| Case size EIA / mm | | A | B | C | D | E |
|-----------------------|------------------|------|------|------|------|------|
| 0201 / 0603 | Single chip | 0.30 | 0.25 | 0.30 | - | - |
| 0402 / 1005 | Single chip | 0.60 | 0.60 | 0.50 | - | - |
| 0508 / 1220 | 2-fold MCV array | 1.00 | 1.30 | 0.40 | 0.60 | 2.16 |
| 0508 / 1220 | 4-fold array | 0.35 | 0.90 | 0.40 | - | 0.50 |
| 0603 / 1608 | Single chip | 1.00 | 1.00 | 1.00 | - | - |
| 0612 / 1632 | 4-fold array | 0.50 | 0.70 | 1.20 | - | 0.76 |

Multilayer varistors (MLVs)
High-speed series
SMD
Delivery mode

| EIA case size | Taping | Reel size mm | Packing unit pcs. | Type | Ordering code |
|---------------------|-----------|-----------------|----------------------|-----------------|-----------------|
| 2-fold array | | | | | |
| 0508 | Cardboard | 180 | 4000 | CA05M2S10T100HG | B72812Q1120S160 |
| 4-fold array | | | | | |
| 0508 | Cardboard | 180 | 4000 | CA05P4S14THSG | B72714A8140S160 |
| 0612 | Blister | 180 | 3000 | CA06P4V150THSG | B72724A8151V062 |
| Single chip | | | | | |
| 0402 | Cardboard | 180 | 10000 | CT0402S14AHSG | B72590T8140S160 |
| 0402 | Cardboard | 180 | 10000 | CT0402S5ARFG | B72590T7050S160 |
| 0402 | Cardboard | 180 | 10000 | CT0402V150HSG | B72590T8151V060 |
| 0402 | Cardboard | 180 | 10000 | CT0402V150RFG | B72590T7151V060 |
| 0402 | Cardboard | 180 | 10000 | CT0402V275RFG | B72590T7271V060 |
| 0402 | Cardboard | 180 | 10000 | CT0402V90RFG | B72590T7900V060 |
| 0603 | Cardboard | 180 | 4000 | CT0603L25HSG | B72500T8250L060 |
| 0603 | Cardboard | 180 | 4000 | CT0603L25HSG_E | B72500E8250L060 |
| 0603 | Cardboard | 180 | 4000 | CT0603S14AHSG | B72500T8140S160 |
| 0603 | Cardboard | 180 | 4000 | CT0603S14AHSG_E | B72500E8140S160 |
| 0603 | Cardboard | 180 | 4000 | CT0603S5ARFG | B72500T7050S160 |
| 0603 | Cardboard | 180 | 4000 | CT0603V150RFG | B72500T7151V060 |
| 0603 | Cardboard | 180 | 4000 | CT0603V150RFG_E | B72500E7151V060 |

Multilayer varistors (MLVs)

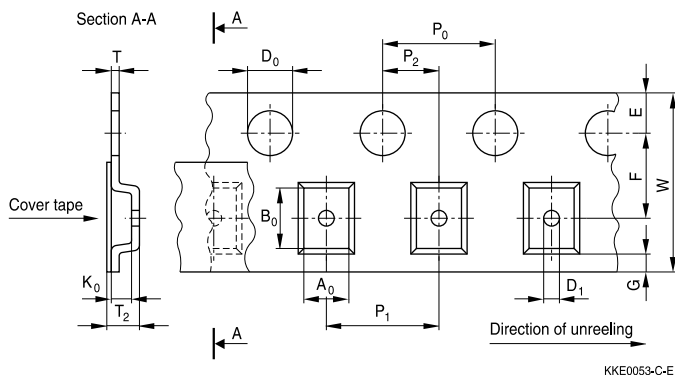
High-speed series

SMD

Taping and packing

1 Taping and packing for SMD components

1.1 Blister tape (taping to IEC 60286-3)



Dimensions in mm

| | 8-mm tape | | | | | 12-mm tape | | Tolerance |
|----------------|---------------------|---------------|---------------|---------------|---------------|---------------------|---------------|---------------------|
| | Case size (inch/mm) | | | | | Case size (inch/mm) | | |
| | | | 0508/ 1220 | 0612/ 1632 | 1012/ 2532 | | | |
| | 0603/ 1608 | 0506/ 1216 | 0805/ 2012 | 1206/ 3216 | 1210/ 3225 | 1812/ 4532 | 2220/ 5750 | |
| A ₀ | 0.9 ±0.10 | 1.50 | 1.50 | 1.80 | 2.80 | 3.50 | 5.10 | ±0.20 |
| B ₀ | 1.75 ±0.10 | 1.80 | 2.30 | 3.40 | 3.50 | 4.80 | 6.00 | ±0.20 |
| K ₀ | 1.0 | 0.80 | 1.80 | | | 3.40 | | max. |
| T | 0.30 | | | | | 0.30 | | max. |
| T ₂ | 1.3 | 1.20 | 2.50 | | | 3.90 | | max. |
| D ₀ | 1.50 | | | | | 1.50 | | +0.10/-0 |
| D ₁ | 0.3 | | | | | 1.50 | | min. |
| P ₀ | 4.00 | | | | | 4.00 | | ±0.10 ¹⁾ |
| P ₂ | 2.00 | | | | | 2.00 | | ±0.05 |
| P ₁ | 4.00 | | | | | 8.00 | | ±0.10 |
| W | 8.00 | | | | | 12.00 | | ±0.30 |
| E | 1.75 | | | | | 1.75 | | ±0.10 |
| F | 3.50 | | | | | 5.50 | | ±0.05 |
| G | 0.75 | | | | | 0.75 | | min. |

1) ≤±0.2 mm over 10 sprocket holes.

Multilayer varistors (MLVs)

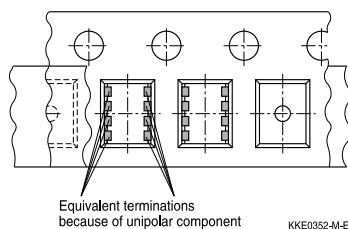
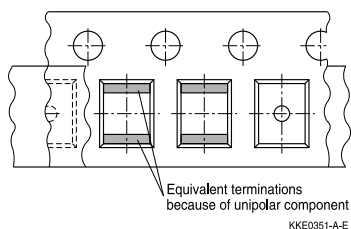
High-speed series

SMD

Part orientation in tape pocket for blister tape

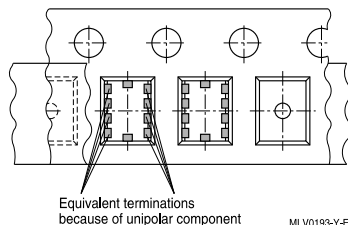
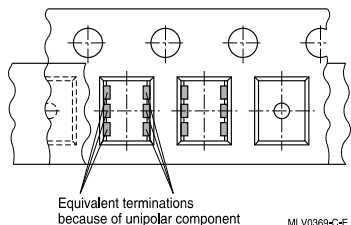
For discrete chip, EIA case sizes 0603, 0805, 1206, 1210, 1812 and 2220

For array, EIA case size 0612



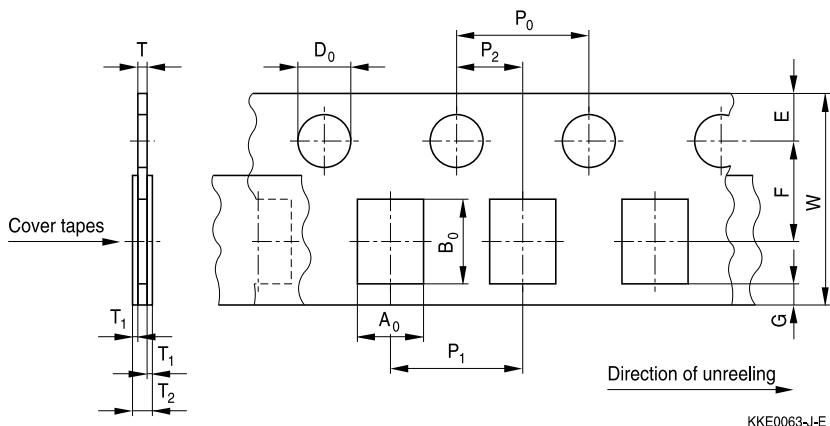
For arrays, EIA case sizes 0506 and 1012

For filter array, EIA case size 0508



Additional taping information

| | |
|---------------------------|-------------------------------------------------------------------------------------------------------------|
| Reel material | Polystyrol (PS) |
| Tape material | Polystyrol (PS) or Polycarbonat (PC) or PVC |
| Tape break force | min. 10 N |
| Top cover tape strength | min. 10 N |
| Top cover tape peel force | 0.1 to 1.0 N for 8-mm tape and 0.1 to 1.3 N for 12-mm tape at a peel speed of 300 mm/min |
| Tape peel angle | Angle between top cover tape and the direction of feed during peel off: 165° to 180° |
| Cavity play | Each part rests in the cavity so that the angle between the part and cavity center line is no more than 20° |

Multilayer varistors (MLVs)
High-speed series
SMD
1.2 Cardboard tape (taping to IEC 60286-3)

Dimensions in mm

| | 8-mm tape | | | | | | Tolerance |
|-------|---------------------|-----------|-----------|-----------|-----------|---------------------|-----------------|
| | Case size (inch/mm) | | | | | Case size (inch/mm) | |
| | 0201/0603 | 0402/1005 | 0405/1012 | 0603/1608 | 1003/2508 | | |
| A_0 | 0.38 ± 0.05 | 0.60 | 1.05 | 0.95 | 1.00 | 1.60 | ± 0.20 |
| B_0 | 0.68 ± 0.05 | 1.15 | 1.60 | 1.80 | 2.85 | 2.40 | ± 0.20 |
| T | 0.42 ± 0.02 | 0.60 | 0.75 | 0.95 | 0.95 | 0.95 | max. |
| T_2 | 0.4 min. | 0.70 | 0.90 | 1.10 | 1.10 | 1.10 | max. |
| D_0 | 1.50 ± 0.1 | 1.50 | | | | 1.50 | $+0.10/-0$ |
| P_0 | 4.00 | | | | | | $\pm 0.10^{2)}$ |
| P_2 | 2.00 | | | | | | ± 0.05 |
| P_1 | 2.00 ± 0.05 | 2.00 | 4.00 | 4.00 | 4.00 | 4.00 | ± 0.10 |
| W | 8.00 | | | | | | ± 0.30 |
| E | 1.75 | | | | | | ± 0.10 |
| F | 3.50 | | | | | | ± 0.05 |
| G | 0.75 | | | | | | min. |

2) ≤ 0.2 mm over 10 sprocket holes.

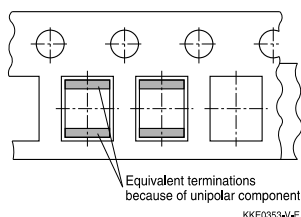
Multilayer varistors (MLVs)

High-speed series

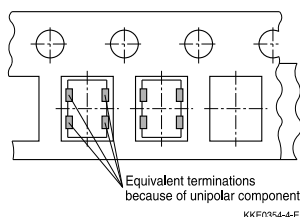
SMD

Part orientation in tape pocket for cardboard tape

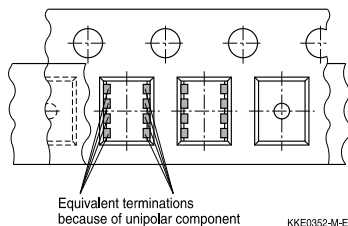
For discrete chip, EIA case sizes 0201, 0402, 0603 and 1003



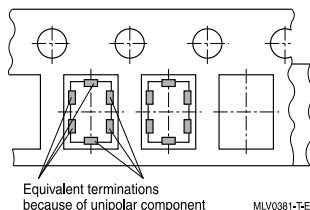
For array, EIA case size 0405



For array, EIA case size 0508



For filter array, EIA case size 0405



Additional taping information

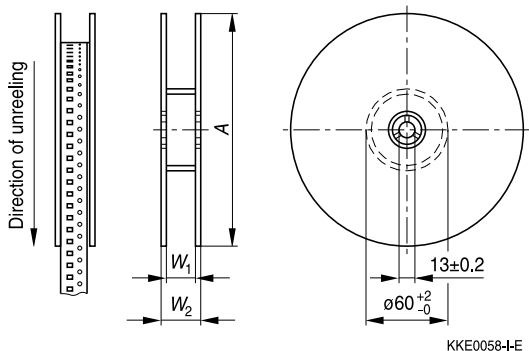
| | |
|---------------------------|-------------------------------------------------------------------------------------------------------------|
| Reel material | Polystyrol (PS) |
| Tape material | Cardboard |
| Tape break force | min. 10 N |
| Top cover tape strength | min. 10 N |
| Top cover tape peel force | 0.1 to 1.0 N at a peel speed of 300 mm/min |
| Tape peel angle | Angle between top cover tape and the direction of feed during peel off: 165° to 180° |
| Cavity play | Each part rests in the cavity so that the angle between the part and cavity center line is no more than 20° |

Multilayer varistors (MLVs)

High-speed series

SMD

1.3 Reel packing

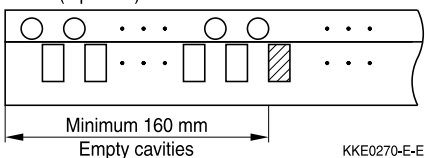


Dimensions in mm

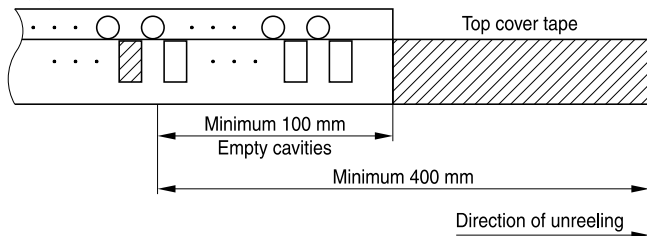
| | 8-mm tape | | 12-mm tape | |
|----------------|-------------|-------------|--------------|--------------|
| | 180-mm reel | 330-mm reel | 180-mm reel | 330-mm reel |
| A | 180 +0/-3 | 330 +0/-2.0 | 180 +0/-3 | 330 +0/-2.0 |
| W ₁ | 8.4 +1.5/-0 | 8.4 +1.5/-0 | 12.4 +1.5/-0 | 12.4 +1.5/-0 |
| W ₂ | 14.4 max. | 14.4 max. | 18.4 max. | 18.4 max. |

Leader, trailer

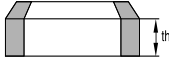
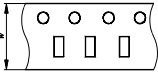


Trailer (tape end)



Leader



Multilayer varistors (MLVs)
High-speed series
SMD
1.4 Packing units for discrete chip and array chip

| Case size inch/mm |  |  | |  |  |
|----------------------|-----------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|-------------------|-----------------------------------------------------------------------------------|------------------------------------------------------------------------------------|
| | Chip thickness th | Cardboard tape W | Blister tape W | ∅ 180-mm reel pcs. | ∅ 330-mm reel pcs. |
| 0201/0603 | 0.33 mm | 8 mm | – | 15000 | – |
| 0402/1005 | 0.6 mm | 8 mm | – | 10000 | 50000 |
| 0405/1012 | 0.7 mm | 8 mm | – | 5000 | – |
| 0506/1216 | 0.5 mm | – | 8 mm | 4000 | – |
| 0508/1220 | 0.9 mm | 8 mm | 8 mm | 4000 | – |
| 0603/1608 | 0.9 mm | 8 mm | 8 mm | 4000 | 16000 |
| 0612/1632 | 0.7 mm | – | 8 mm | 3000 | – |
| 0805/2012 | 0.7 mm | – | 8 mm | 3000 | – |
| | 0.9 mm | – | 8 mm | 3000 | 12000 |
| | 1.3 mm | – | 8 mm | 3000 | 12000 |
| 1003/2508 | 0.9 mm | 8 mm | – | 4000 | – |
| 1012/2532 | 1.0 mm | – | 8 mm | 2000 | – |
| 1206/3216 | 0.9 mm | – | 8 mm | 3000 | – |
| | 1.3 mm | – | 8 mm | 3000 | 12000 |
| | 1.4 mm | – | 8 mm | 2000 | 8000 |
| | 1.6 mm | – | 8 mm | 2000 | 8000 |
| 1210/3225 | 0.9 mm | – | 8 mm | 3000 | – |
| | 1.3 mm | – | 8 mm | 3000 | 12000 |
| | 1.4 mm | – | 8 mm | 2000 | 8000 |
| | 1.6 mm | – | 8 mm | 2000 | 8000 |
| 1812/4532 | 1.3 mm | – | 12 mm | 1500 | – |
| | 1.4 mm | – | 12 mm | 1000 | – |
| | 1.6 mm | – | 12 mm | 1000 | 4000 |
| | 2.0 mm | – | 12 mm | – | 3000 |
| | 2.3 mm | – | 12 mm | – | 3000 |
| 2220/5750 | 1.3 mm | – | 12 mm | 1500 | – |
| | 1.4 mm | – | 12 mm | 1000 | – |
| | 1.6 mm | – | 12 mm | 1000 | – |
| | 2.0 mm | – | 12 mm | – | 3000 |
| | 2.3 mm | – | 12 mm | – | 3000 |
| | 2.7 mm | – | 12 mm | 600 | – |
| | 3.0 mm | – | 12 mm | 600 | – |

Multilayer varistors (MLVs)**High-speed series****SMD****2 Delivery mode for leaded SHCV varistors**

Standard delivery mode for SHCV types is bulk. Alternative taping modes (AMMO pack or taped on reel) are available upon request.

Packing units for:

| Type | Pieces |
|-----------|--------|
| SR6 | 2000 |
| SR1 / SR2 | 1000 |

For types not listed in this data book please contact TDK Electronics.

Multilayer varistors (MLVs)

High-speed series

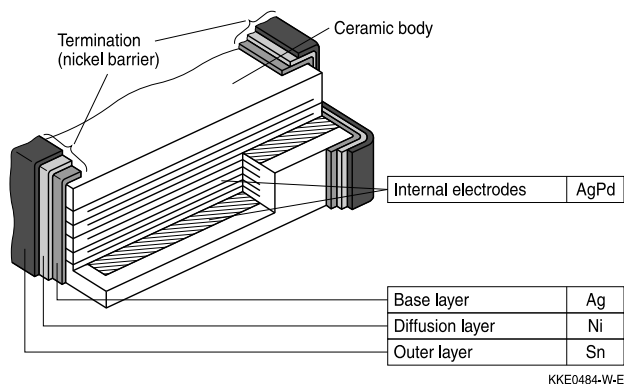
SMD

Soldering directions

1 Terminations and soldering methods

1.1 Nickel barrier termination

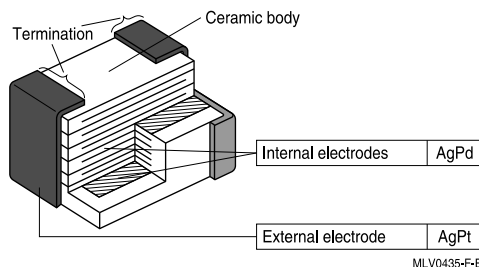
The nickel barrier layer of the silver/nickel/tin termination prevents leaching of the silver base metallization layer. This allows great flexibility in the selection of soldering parameters. The tin prevents the nickel layer from oxidizing and thus ensures better wetting by the solder. The nickel barrier termination is suitable for lead-free soldering, as well as for other commonly-used soldering methods.



Multilayer CTVS: Structure of nickel barrier termination

1.2 Silver-platinum termination

Silver-platinum terminations are mainly used for the large EIA case sizes 1812 and 2220. The silver-platinum termination is approved for reflow soldering, SnPb soldering and lead-free soldering with a silver containing solder paste. In case of SnPb soldering, a solder paste Sn62Pb36Ag2 is recommended. For lead-free reflow soldering, a solder paste SAC, e.g. Sn95.5Ag3.8Cu0.7, is recommended.



Multilayer varistor: Structure of silver-platinum termination

Multilayer varistors (MLVs)

High-speed series

SMD

1.3 Silver-palladium termination

Silver-palladium terminations are designed for the use of conductive adhesives. Lead-free reflow soldering does not form a proper solder joint. In general reflow or wave soldering is not recommended.

1.4 Tinned iron wire

All SHCV types with tinned terminations are suitable for lead-free and SnPb soldering.

Multilayer varistors (MLVs)

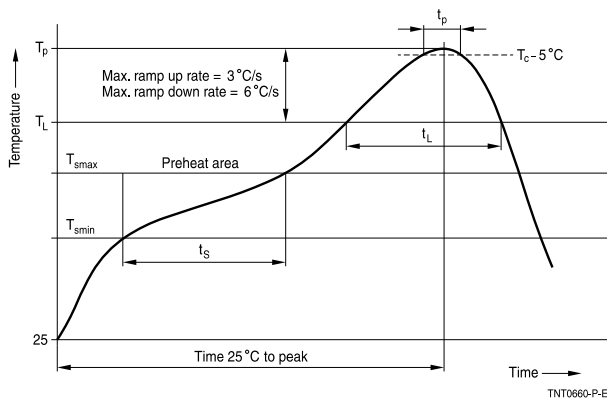
High-speed series

SMD

2 Recommended soldering temperature profiles

2.1 Reflow soldering temperature profile

Temperature ranges for reflow soldering acc. to IEC 60068-2-58 recommendations.



| Profile feature | | Sn-Pb eutectic assembly | Pb-free assembly |
|--------------------------------|--------------------------|---------------------------------|-------------------|
| Preheat and soak | | | |
| - Temperature min | T_{smin} | 100 °C | 150 °C |
| - Temperature max | T_{smax} | 150 °C | 200 °C |
| - Time | t_{smin} to t_{smax} | 60 ... 120 s | 60 ... 120 s |
| Average ramp-up rate | T_{smax} to T_p | 3 °C/ s max. | 3 °C/ s max. |
| Liquidous temperature | T_L | 183 °C | 217 °C |
| Time at liquidous | t_L | 40 ... 150 s | 40 ... 150 s |
| Peak package body temperature | T_p | 215 °C ... 260 °C ¹⁾ | 235 °C ... 260 °C |
| Time above ($T_p - 5$ °C) | t_p | 10 ... 40 s | 10 ... 40 s |
| Average ramp-down rate | T_p to T_{smax} | 6 °C/ s max. | 6 °C/ s max. |
| Time 25 °C to peak temperature | | max. 8 minutes | max. 8 minutes |

1) Depending on package thickness.

Notes: All temperatures refer to topside of the package, measured on the package body surface.

Number of reflow cycles: 3

Iron soldering should be avoided, hot air methods are recommended for repair purposes.

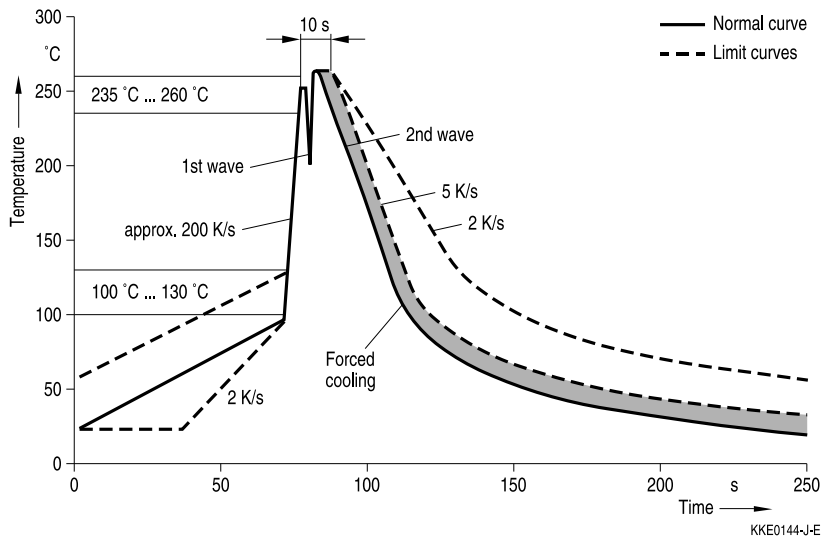
Multilayer varistors (MLVs)

High-speed series

SMD

2.2 Wave soldering temperature profile

Temperature characteristics at component terminal with dual-wave soldering



3 Solder joint profiles / solder quantity

3.1 Nickel barrier termination

If the meniscus height is too low, that means the solder quantity is too low, the solder joint may break, i.e. the component becomes detached from the joint. This problem is sometimes interpreted as leaching of the external terminations.

If the solder meniscus is too high, i.e. the solder quantity is too large, the vise effect may occur. As the solder cools down, the solder contracts in the direction of the component. If there is too much solder on the component, it has no leeway to evade the stress and may break, as in a vise.

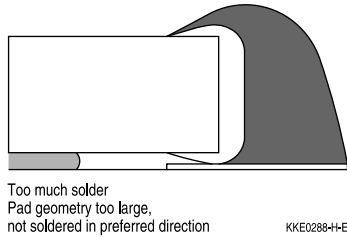
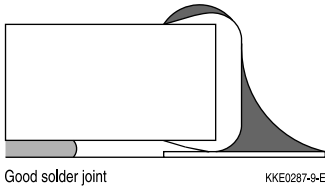
The figures below show good and poor solder joints for dual-wave and infrared soldering.

Multilayer varistors (MLVs)

High-speed series

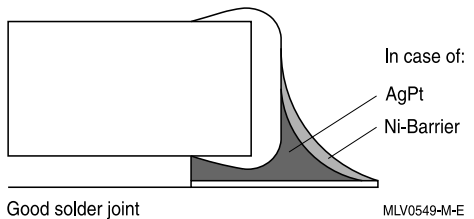
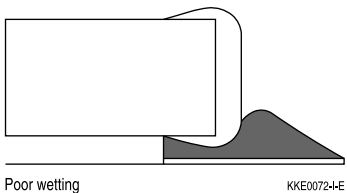
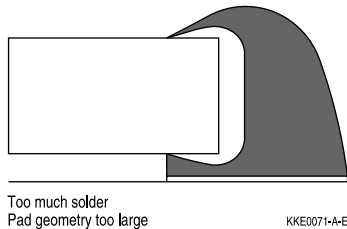
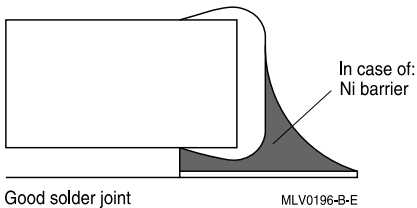
SMD

3.1.1 Solder joint profiles for nickel barrier termination - dual-wave soldering



Good and poor solder joints caused by amount of solder in dual-wave soldering.

3.1.2 Solder joint profiles for nickel barrier termination / silver-platinum termination - reflow soldering



Good and poor solder joints caused by amount of solder in reflow soldering.

Multilayer varistors (MLVs)
High-speed series
SMD
4 Solderability tests

| Test | Standard | Test conditions Sn-Pb soldering | Test conditions Pb-free soldering | Criteria/ test results |
|---------------------------------------------------------------------------------------|-------------------|--------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------|
| Wettability | IEC 60068-2-58 | Immersion in 60/40 SnPb solder using non-activated flux at 215 ±3 °C for 3 ±0.3 s | Immersion in Sn96.5Ag3.0Cu0.5 solder using non- or low activated flux at 245 ±5 °C for 3 ±0.3 s | Covering of 95% of end termination, checked by visual inspection |
| Leaching resistance | IEC 60068-2-58 | Immersion in 60/40 SnPb solder using mildly activated flux without preheating at 260 ±5 °C for 10 ±1 s | Immersion in Sn96.5Ag3.0Cu0.5 solder using non- or low activated flux without preheating at 255 ±5 °C for 10 ±1 s | No leaching of contacts |
| Thermal shock (solder shock) | | Dip soldering at 300 °C/5 s | Dip soldering at 300 °C/5 s | No deterioration of electrical parameters. Capacitance change: $ \Delta C/C_0 \leq 15\%$ |
| Tests of resistance to soldering heat for SMDs | IEC 60068-2-58 | Immersion in 60/40 SnPb for 10 s at 260 °C | Immersion in Sn96.5Ag3.0Cu0.5 for 10 s at 260 °C | Change of varistor voltage: $ \Delta V/V (1 \text{ mA}) \leq 5\%$ |
| Tests of resistance to soldering heat for radial leaded components (SHCV) | IEC 60068-2-20 | Immersion of leads in 60/40 SnPb for 10 s at 260 °C | Immersion of leads in Sn96.5Ag3.0Cu0.5 for 10 s at 260 °C | Change of varistor voltage: $ \Delta V/V (1 \text{ mA}) \leq 5\%$ Change of capacitance X7R: $\leq -5/+10\%$ |

Multilayer varistors (MLVs)

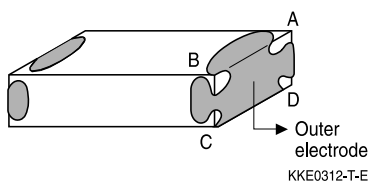
High-speed series

SMD

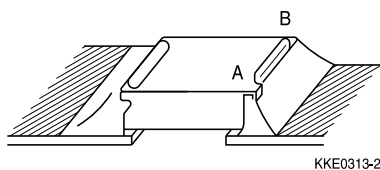
Note:

Leaching of the termination

Effective area at the termination might be lost if the soldering temperature and/or immersion time are not kept within the recommended conditions. Leaching of the outer electrode should not exceed 25% of the chip end area (full length of the edge A-B-C-D) and 25% of the length A-B, shown below as mounted on substrate.



As a single chip



As mounted on substrate

5 Notes for proper soldering

5.1 Preheating and cooling

- According to IEC 60068-2-58. Please refer to section 2 of this chapter.

5.2 Repair/ rework

Manual soldering with a soldering iron must be avoided, hot-air methods are recommended for rework purposes.

5.3 Cleaning

All environmentally compatible agents are suitable for cleaning. Select the appropriate cleaning solution according to the type of flux used. The temperature difference between the components and cleaning liquid must not be greater than 100 °C. Ultrasonic cleaning should be carried out with the utmost caution. Too high ultrasonic power can impair the adhesive strength of the metalized surfaces.

5.4 Solder paste printing (reflow soldering)

An excessive application of solder paste results in too high a solder fillet, thus making the chip more susceptible to mechanical and thermal stress. Too little solder paste reduces the adhesive strength on the outer electrodes and thus weakens the bonding to the PCB. The solder should be applied smoothly to the end surface.

Multilayer varistors (MLVs)

High-speed series

SMD

5.5 Selection of flux

Used flux should have less than or equal to 0.1 wt % of halogenated content, since flux residue after soldering could lead to corrosion of the termination and/or increased leakage current on the surface of the component. Strong acidic flux must not be used. The amount of flux applied should be carefully controlled, since an excess may generate flux gas, which in turn is detrimental to solderability.

5.6 Storage of CTVSs

Solderability is guaranteed for one year from date of delivery for multilayer varistors, CeraDiodes and ESD/EMI filters (half a year for chips with AgPt terminations) and two years for SHCV components, provided that components are stored in their original packages.

Storage temperature: –25 °C to +45 °C

Relative humidity: ≤75% annual average, ≤95% on 30 days a year

The solderability of the external electrodes may deteriorate if SMDs and leaded components are stored where they are exposed to high humidity, dust or harmful gas (hydrogen chloride, sulfuric acid gas or hydrogen sulfide).

Do not store SMDs and leaded components where they are exposed to heat or direct sunlight. Otherwise the packing material may be deformed or SMDs/ leaded components may stick together, causing problems during mounting.

After opening the factory seals, such as polyvinyl-sealed packages, it is recommended to use the SMDs or leaded components as soon as possible.

Solder CTVS components after shipment from TDK Electronics within the time specified:

CTVS with Ni barrier termination: 12 months

CTVS with AgPt termination: 6 months

SHCV (leaded components): 24 months

5.7 Placement of components on circuit board

Especially in the case of dual-wave soldering, it is of advantage to place the components on the board before soldering in that way that their two terminals do not enter the solder bath at different times.

Ideally, both terminals should be wetted simultaneously.

Multilayer varistors (MLVs)

High-speed series

SMD

5.8 Soldering cautions

An excessively long soldering time or high soldering temperature results in leaching of the outer electrodes, causing poor adhesion and a change of electrical properties of the varistor due to the loss of contact between electrodes and termination.

Keep the recommended down-cooling rate.

5.9 Standards

CECC 00802

IEC 60068-2-58

IEC 60068-2-20

Multilayer varistors (MLVs)

High-speed series

SMD

Symbols and terms

For ceramic transient voltage suppressors (CTVS)

| Symbol | Term |
|-------------------|--------------------------------------------------|
| $C_{line,max}$ | Maximum capacitance per line |
| $C_{line,min}$ | Minimum capacitance per line |
| $C_{line,typ}$ | Typical capacitance per line |
| C_{max} | Maximum capacitance |
| C_{min} | Minimum capacitance |
| C_{nom} | Nominal capacitance |
| ΔC_{nom} | Tolerance of nominal capacitance |
| C_{typ} | Typical capacitance |
| $f_{cut-off,max}$ | Maximum cut-off frequency |
| $f_{cut-off,min}$ | Minimum cut-off frequency |
| $f_{cut-off,typ}$ | Typical cut-off frequency |
| $f_{res,typ}$ | Typical resonance frequency |
| I | Current |
| I_{clamp} | Clamping current |
| I_{leak} | Leakage current |
| $I_{leak,max}$ | Maximum leakage current |
| $I_{leak,typ}$ | Typical leakage current |
| I_{PP} | Peak pulse current |
| $I_{surge,max}$ | Maximum surge current (also termed peak current) |
| LCT | Lower category temperature |
| L_{typ} | Typical inductance |
| $P_{diss,max}$ | Maximum power dissipation |
| P_{PP} | Peak pulse power |
| R_{ins} | Insulation resistance |
| R_{min} | Minimum resistance |
| R_S | Resistance per line |
| $R_{S,typ}$ | Typical resistance per line |
| T_A | Ambient temperature |
| T_{op} | Operating temperature |
| $T_{op,max}$ | Maximum operating temperature |
| T_{stg} | Storage temperature |

Multilayer varistors (MLVs)
High-speed series
SMD

| Symbol | Term |
|-------------------|------------------------------------------------------------|
| t_r | Duration of equivalent rectangular wave |
| t_{resp} | Response time |
| $t_{resp,max}$ | Maximum response time |
| UCT | Upper category temperature |
| V | Voltage |
| $V_{BR,min}$ | Minimum breakdown voltage |
| $V_{clamp,max}$ | Maximum clamping voltage |
| $V_{DC,max}$ | Maximum DC operating voltage (also termed working voltage) |
| $V_{ESD,air}$ | Air discharge ESD capability |
| $V_{ESD,contact}$ | Contact discharge ESD capability |
| V_{jump} | Maximum jump-start voltage |
| $V_{RMS,max}$ | Maximum AC operating voltage, root-mean-square value |
| V_V | Varistor voltage (also termed breakdown voltage) |
| V_{LD} | Maximum load dump voltage |
| V_{leak} | Measurement voltage for leakage current |
| $V_{V,min}$ | Minimum varistor voltage |
| $V_{V,max}$ | Maximum varistor voltage |
| ΔV_V | Tolerance of varistor voltage |
| W_{LD} | Maximum load dump energy |
| W_{max} | Maximum energy absorption (also termed transient energy) |
| α_{typ} | Typical insertion loss |
| $\tan \delta$ | Dissipation factor |
| e | Lead spacing |
| $\ll * \gg$ | Maximum possible application conditions |

All dimensions are given in mm.

The commas used in numerical values denote decimal points.

Multilayer varistors (MLVs)

High-speed series

SMD

Cautions and warnings

General

Some parts of this publication contain statements about the suitability of our ceramic transient voltage suppressor (CTVS) components (multilayer varistors (MLVs)), CeraDiodes, ESD/EMI filters, leaded transient voltage/ RFI suppressors (SHCV types)) for certain areas of application, including recommendations about incorporation/design-in of these products into customer applications. The statements are based on our knowledge of typical requirements often made of our CTVS devices in the particular areas. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our CTVS components for a particular customer application. As a rule, TDK Electronics is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always incumbent on the customer to check and decide whether the CTVS devices with the properties described in the product specification are suitable for use in a particular customer application.

- Do not use TDK CTVS components for purposes not identified in our specifications, application notes and data books.
- Ensure the suitability of a CTVS in particular by testing it for reliability during design-in. Always evaluate a CTVS component under worst-case conditions.
- Pay special attention to the reliability of CTVS devices intended for use in safety-critical applications (e.g. medical equipment, automotive, spacecraft, nuclear power plant).

Design notes

- Always connect a CTVS in parallel with the electronic circuit to be protected.
- Consider maximum rated power dissipation if a CTVS has insufficient time to cool down between a number of pulses occurring within a specified isolated time period. Ensure that electrical characteristics do not degrade.
- Consider derating at higher operating temperatures. Choose the highest voltage class compatible with derating at higher temperatures.
- Surge currents beyond specified values will puncture a CTVS. In extreme cases a CTVS will burst.
- If steep surge current edges are to be expected, make sure your design is as low-inductance as possible.
- In some cases the malfunctioning of passive electronic components or failure before the end of their service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. In applications requiring a very high level of operational safety and especially when the malfunction or failure of a passive electronic component could endanger human life or health (e.g. in accident prevention, life-saving systems, or automotive battery line applications such as clamp 30), ensure by suitable design of the application or other measures (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of such a malfunction or failure. Only use CTVS components from the automotive series in safety-relevant applications.

Multilayer varistors (MLVs)

High-speed series

SMD

- Specified values only apply to CTVS components that have not been subject to prior electrical, mechanical or thermal damage. The use of CTVS devices in line-to-ground applications is therefore not advisable, and it is only allowed together with safety countermeasures like thermal fuses.

Storage

- Only store CTVS in their original packaging. Do not open the package prior to processing.
- Storage conditions in original packaging: temperature -25 to $+45^{\circ}\text{C}$, relative humidity $\leq 75\%$ annual average, maximum 95%, dew precipitation is inadmissible.
- Do not store CTVS devices where they are exposed to heat or direct sunlight. Otherwise the packaging material may be deformed or CTVS may stick together, causing problems during mounting.
- Avoid contamination of the CTVS surface during storage, handling and processing.
- Avoid storing CTVS devices in harmful environments where they are exposed to corrosive gases for example (SO_x , Cl).
- Use CTVS as soon as possible after opening factory seals such as polyvinyl-sealed packages.
- Solder CTVS components after shipment from TDK Electronics within the time specified:
 - CTVS with Ni barrier termination, 12 months
 - CTVS with AgPt termination, 6 months
 - SHCV, 24 months

Handling

- Do not drop CTVS components and allow them to be chipped.
- Do not touch CTVS with your bare hands - gloves are recommended.
- Avoid contamination of the CTVS surface during handling.
- Washing processes may damage the product due to the possible static or cyclic mechanical loads (e.g. ultrasonic cleaning). They may cause cracks to develop on the product and its parts, which might lead to reduced reliability or lifetime.

Mounting

- When CTVS devices are encapsulated with sealing material or overmolded with plastic material, electrical characteristics might be degraded and the life time reduced.
- Make sure an electrode is not scratched before, during or after the mounting process.
- Make sure contacts and housings used for assembly with CTVS components are clean before mounting.
- The surface temperature of an operating CTVS can be higher. Ensure that adjacent components are placed at a sufficient distance from a CTVS to allow proper cooling.
- Avoid contamination of the CTVS surface during processing.

Multilayer varistors (MLVs)

High-speed series

SMD

Soldering

- Complete removal of flux is recommended to avoid surface contamination that can result in an instable and/or high leakage current.
- Use resin-type or non-activated flux.
- Bear in mind that insufficient preheating may cause ceramic cracks.
- Rapid cooling by dipping in solvent is not recommended, otherwise a component may crack.

Operation

- Use CTVS only within the specified operating temperature range.
- Use CTVS only within specified voltage and current ranges.
- Environmental conditions must not harm a CTVS. Only use them in normal atmospheric conditions. Reducing the atmosphere (e.g. hydrogen or nitrogen atmosphere) is prohibited.
- Prevent a CTVS from contacting liquids and solvents. Make sure that no water enters a CTVS (e.g. through plug terminals).
- Avoid dewing and condensation.
- TDK CTVS components are mainly designed for encased applications. Under all circumstances avoid exposure to:
 - direct sunlight
 - rain or condensation
 - steam, saline spray
 - corrosive gases
 - atmosphere with reduced oxygen content
- TDK CTVS devices are not suitable for switching applications or voltage stabilization where static power dissipation is required.

This listing does not claim to be complete, but merely reflects the experience of TDK Electronics AG.

Display of ordering codes for TDK Electronics products

The ordering code for one and the same product can be represented differently in data sheets, data books, other publications, on the company website, or in order-related documents such as shipping notes, order confirmations and product labels. **The varying representations of the ordering codes are due to different processes employed and do not affect the specifications of the respective products.** Detailed information can be found on the Internet under www.tdk-electronics.tdk.com/orderingcodes.

Important notes

The following applies to all products named in this publication:

1. Some parts of this publication contain **statements about the suitability of our products for certain areas of application**. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out **that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application**. As a rule we are either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether a product with the properties described in the product specification is suitable for use in a particular customer application.
2. We also point out that **in individual cases, a malfunction of electronic components or failure before the end of their usual service life cannot be completely ruled out in the current state of the art, even if they are operated as specified**. In customer applications requiring a very high level of operational safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health (e.g. in accident prevention or life-saving systems), it must therefore be ensured by means of suitable design of the customer application or other action taken by the customer (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of malfunction or failure of an electronic component.
3. **The warnings, cautions and product-specific notes must be observed.**
4. In order to satisfy certain technical requirements, **some of the products described in this publication may contain substances subject to restrictions in certain jurisdictions (e.g. because they are classed as hazardous)**. Useful information on this will be found in our Material Data Sheets on the Internet (www.tdk-electronics.tdk.com/material). Should you have any more detailed questions, please contact our sales offices.
5. We constantly strive to improve our products. Consequently, **the products described in this publication may change from time to time**. The same is true of the corresponding product specifications. Please check therefore to what extent product descriptions and specifications contained in this publication are still applicable before or when you place an order. We also **reserve the right to discontinue production and delivery of products**. Consequently, we cannot guarantee that all products named in this publication will always be available. The aforementioned does not apply in the case of individual agreements deviating from the foregoing for customer-specific products.
6. Unless otherwise agreed in individual contracts, **all orders are subject to our General Terms and Conditions of Supply**.

7. **Our manufacturing sites serving the automotive business apply the IATF 16949 standard.**
The IATF certifications confirm our compliance with requirements regarding the quality management system in the automotive industry. Referring to customer requirements and customer specific requirements (“CSR”) TDK always has and will continue to have the policy of respecting individual agreements. Even if IATF 16949 may appear to support the acceptance of unilateral requirements, we hereby like to emphasize that **only requirements mutually agreed upon can and will be implemented in our Quality Management System.** For clarification purposes we like to point out that obligations from IATF 16949 shall only become legally binding if individually agreed upon.
8. The trade names EPCOS, CarXield, CeraCharge, CeraDiode, CeraLink, CeraPad, CeraPlas, CSMP, CTVS, DeltaCap, DigiSiMic, FilterCap, FormFit, InsuGate, LeaXield, MediPlas, MiniBlue, MiniCell, MKD, MKK, ModCap, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, PiezoBrush, PlasmaBrush, PowerHap, PQSine, PQvar, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SiMic, SIMID, SineFormer, SIOV, SurfIND, ThermoFuse, WindCap, XieldCap are **trademarks registered or pending** in Europe and in other countries. Further information will be found on the Internet at www.tdk-electronics.tdk.com/trademarks.

Release 2024-02